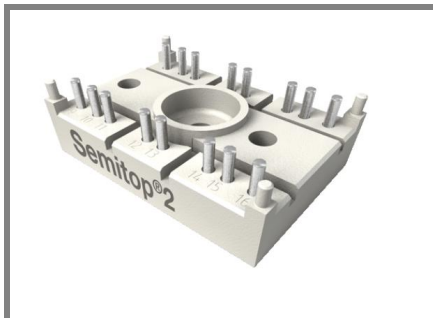


# SK 35 TAA



**SEMITOP®2**

## Two separated thyristors

### SK 35 TAA

#### Target Data

#### Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passivated thyristor chips
- Up to 1600 reverse voltage
- High surge currents

#### Typical Applications

- Brake chopper
- Soft starters

| $V_{RSM}$<br>V | $V_{RRM}, V_{DRM}$<br>V | $I_T = 35$ A<br>( $T_s = 80$ °C) |
|----------------|-------------------------|----------------------------------|
| 900            | 800                     | SK35TAA08                        |
| 1300           | 1200                    | SK35TAA12                        |
| 1700           | 1600                    | SK35TAA16                        |

#### Characteristics $T_s = 25$ °C unless otherwise specified

| Symbol            | Conditions                                    | Values       | Units            |
|-------------------|---|--------------|------------------|
| $I_T$             | $T_s = 100$ °C                                | 23           | A                |
| $I_T$             | $T_s = 80$ °C                                 | 35           | A                |
|                   |   |              | A                |
| $I_{TSM}/I_{FSM}$ | $T_{vj} = 25$ (125) °C; 10 ms                 | 450 (380)    | A                |
| $I^2t$            | $T_{vj} = 25$ (125) °C; half sine wave, 10 ms | 1000 (720)   | A <sup>2</sup> s |
| $T_{stg}$         |   | -40 ... +125 | °C               |
| $T_{solder}$      | terminals, 10 s                               | 260          | °C               |

#### Thyristor

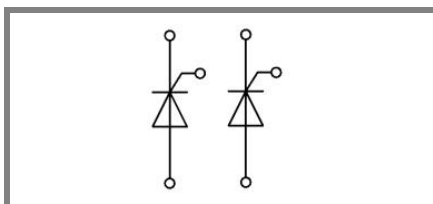
|                  |   |              |            |
|------------------|---|--------------|------------|
| $(dv/dt)_{cr}$   | $T_{vj} = 125$ °C                                       | 1000         | V/ $\mu$ s |
| $(di/dt)_{cr}$   | $T_{vj} = 125$ °C; $f = 50 \dots 60$ Hz                 | 50           | A/ $\mu$ s |
| $t_q$            | $T_{vj} = 125$ °C; typ.                                 | 120          | $\mu$ s    |
| $I_H$            | $T_{vj} = 25$ °C; typ. / max.                           | 80 / 150     | mA         |
| $I_L$            | $T_{vj} = 25$ °C; $R_G = 33$ $\Omega$ ; typ. / max.     | 150 / 300    | mA         |
| $V_T$            | $T_{vj} = 25$ °C; ( $I_T = 75$ A); max.                 | 1,9          | V          |
| $V_{T(TO)}$      | $T_{vj} = 125$ °C                                       | max. 0,85    | V          |
| $r_T$            | $T_{vj} = 125$ °C                                       | max. 9,1     | m $\Omega$ |
| $I_{DD}, I_{RD}$ | $T_{vj} = 125$ °C; $V_{DD} = V_{DRM}, V_{RD} = V_{RRM}$ | max. 10      | mA         |
| $R_{th(j-s)}$    | cont. per thyristor                                     | 1,2          | K/W        |
| $T_{vj}$         |   | -40 ... +125 | °C         |
| $V_{GT}$         | $T_{vj} = 25$ °C; d.c.                                  | 3            | V          |
| $I_{GT}$         | $T_{vj} = 25$ °C; d.c.                                  | 100          | mA         |
| $V_{GD}$         | $T_{vj} = 125$ °C; d.c.                                 | 0,25         | V          |
| $I_{GD}$         | $T_{vj} = 125$ °C; d.c.                                 | 3            | mA         |

#### Diode

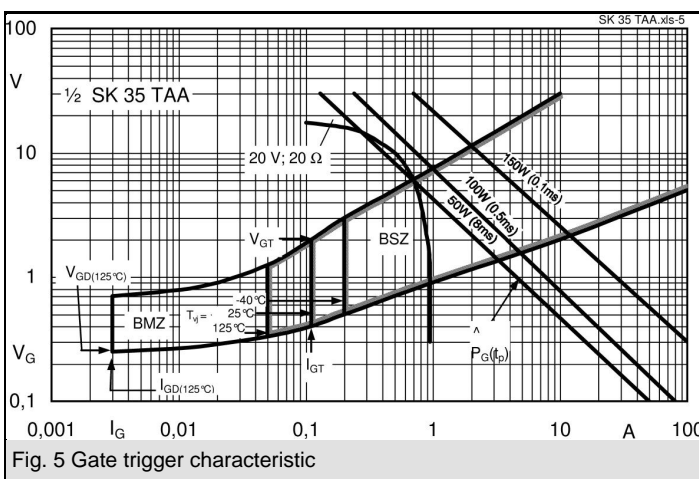
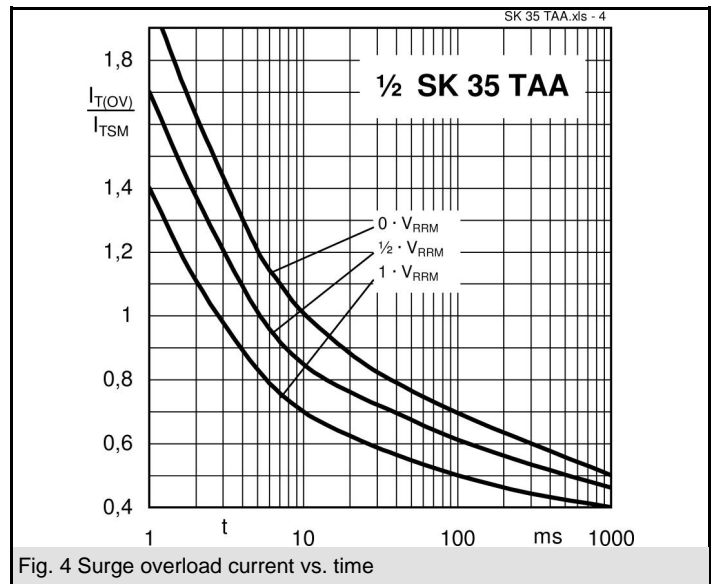
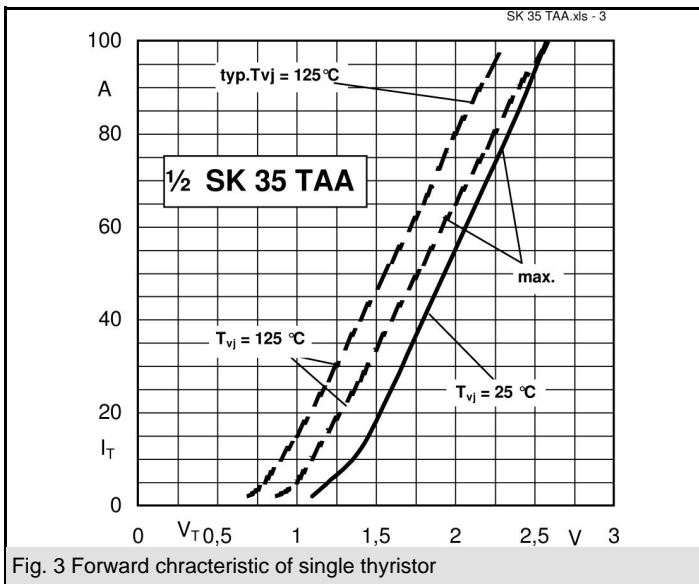
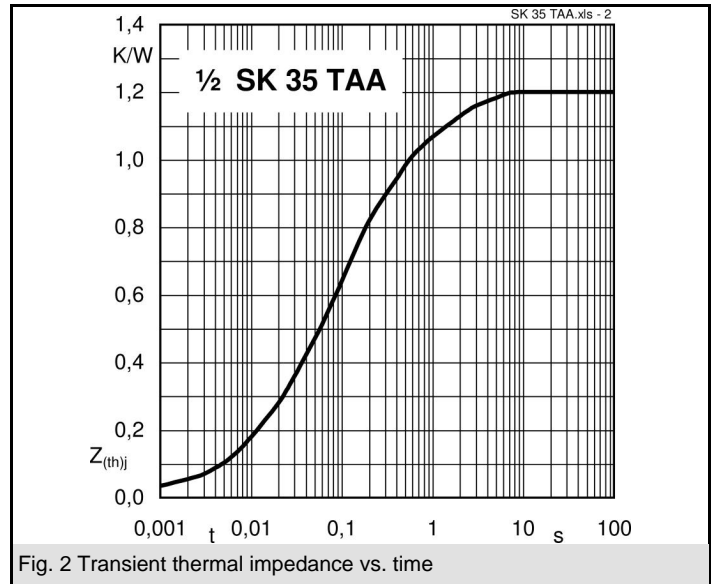
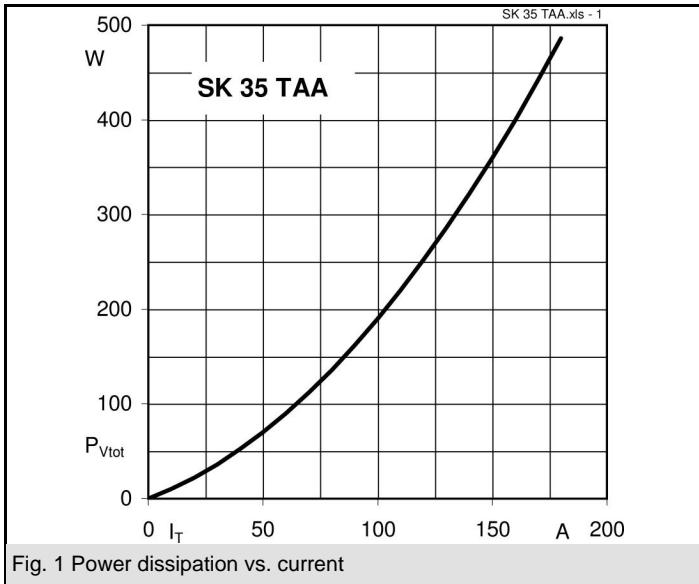
|               |                                   |  |            |
|---------------|-----------------------------------|--|------------|
| $V_F$         | $T_{vj} =$ °C; ( $I_F =$ A); max. |  | V          |
| $V_{(TO)}$    | $T_{vj} =$ °C                     |  | V          |
| $r_T$         | $T_{vj} =$ °C                     |  | m $\Omega$ |
| $I_{RD}$      | $T_{vj} =$ °C; $V_{RD} = V_{RRM}$ |  | mA         |
| $R_{th(j-s)}$ |                                   |  | K/W        |
| $T_{vj}$      |                                   |  | °C         |

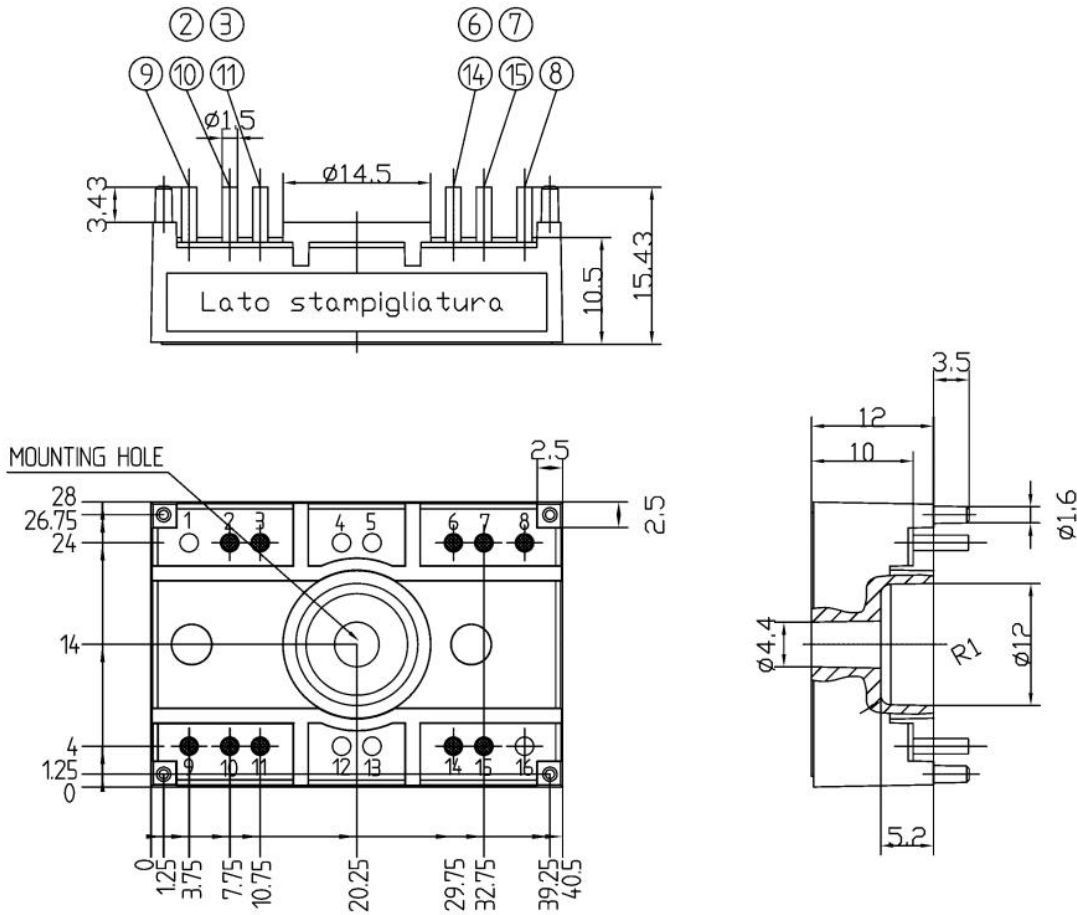
#### Mechanical data

|            |                             |             |    |
|------------|-----------------------------|-------------|----|
| $V_{isol}$ | AC 50Hz, r.m.s. 1min (1sec) | 2500 (3000) | V  |
| $M_1$      | mounting torque             | 2           | Nm |
| w          |                             | 19          | g  |
| Case       | SEMITOP®2                   | T 81        |    |



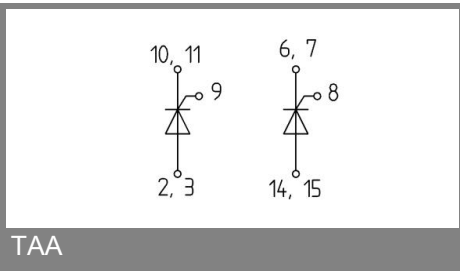
TAA





SUGGESTED HOLEDIAMETER FOR THE SOLDER PINS AND THE MOUNTING PINS IN THE PCB: 2 mm

Case T 81 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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